



HIP6601BECB Information



For Reference Only

Part Number HIP6601BECB

Manufacturer Renesas Electronics America

Category Integrated Circuits (ICs)
PMIC - Gate Drivers

DescriptionIC DRVR MOSFET SYNC BUCK 8EPSOIC**Package**8-SOIC (0.154", 3.90mm Width) Exposed Pad

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



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HIP6601BECB Specifications

Manufacturer Part NumberHIP6601BECBManufacturerRenesas Electronics AmericaCategoryIntegrated Circuits (ICs)Package8-SOIC (0.154", 3.90mm Width) Exposed PadSeries-Driven ConfigurationHalf-BridgeChannel TypeSynchronousNumber of Drivers2Gate TypeN-Channel MOSFETVoltage - Supply10.8 V ~ 13.2 VLogic Voltage - VIL, VIH-Current - Peak Output (Source, Sink)-Input TypeNon-InvertingHigh Side Voltage - Max (Bootstrap)15VRise / Fall Time (Typ)20ns, 20nsOperating Temperature0°C ~ 125°C (TJ)Mounting TypeSurface MountPackage / Case8-SOIC (0.154", 3.90mm Width) Exposed PadSupplier Device Package8-SOIC-EP		
Category Integrated Circuits (ICs) PMIC - Gate Drivers Package 8-SOIC (0.154", 3.90mm Width) Exposed Pad Series - Driven Configuration Half-Bridge Channel Type Synchronous Number of Drivers 2 Gate Type N-Channel MOSFET Voltage - Supply 10.8 V ~ 13.2 V Logic Voltage - VIL, VIH - Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) 15V Rise / Fall Time (Typ) Operating Temperature 0°C ~ 125°C (TJ) Mounting Type Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Manufacturer Part Number	HIP6601BECB
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Gate Type N-Channel MOSFET 10.8 V ~ 13.2 V Logic Voltage - VIL, VIH - Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Channel Type	Synchronous
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Logic Voltage - VIL, VIH Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature O°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Gate Type	N-Channel MOSFET
Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature O°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Voltage - Supply	10.8 V ~ 13.2 V
Input Type Non-Inverting High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature O°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Logic Voltage - VIL, VIH	-
High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature O°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Current - Peak Output (Source, Sink)	-
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Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package 8-SOIC-EP	Rise / Fall Time (Typ)	20ns, 20ns
Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package 8-SOIC-EP	Operating Temperature	0°C ~ 125°C (TJ)
Supplier Device Package 8-SOIC-EP	Mounting Type	Surface Mount
	Package / Case	8-SOIC (0.154", 3.90mm Width) Exposed Pad
Report errors?	Supplier Device Package	8-SOIC-EP
		Report errors?

HIP6601BECB Guarantees



Quality Guarantees

We provide 90 days warranty. *

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Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

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